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Application Number:	10814482					
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First Named Inventor/Applicant Name:	Toshiharu Furukawa					
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1	Information Disclosure Statement (IDS) Filed (SB/08)	ROC920030399US1_IDS_11-09- 10.pdf	612392 7210001337364423adb9c20d098c73419c0 23262	no	4			

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If a timely submission to enter the national stage of an international application is compliant with the conditions of 35 U.S.C. 371 and other applicable requirements a Form PCT/DO/EO/903 indicating acceptance of the application as a national stage submission under 35 U.S.C. 371 will be issued in addition to the Filing Receipt, in due course.

### New International Application Filed with the USPTO as a Receiving Office

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